CD74FCT245 BICMOS OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS SCBS721 – JULY 2000

| • | BiCMOS Technology With Low Quiescent Power | , , | M PACKAGE VIEW) |
|---|---|-------------|---------------------|
| ٠ | Buffered Inputs | | 20] V _{CC} |
| • | Noninverted Outputs | A1 [] 2 | 19 0E |
| ٠ | Input/Output Isolation From V _{CC} | A2 🛛 3 | 18 B1 |
| • | Controlled Output Edge Rates | A3 🛛 4 | 17 B2 |
| | 64-mA Output Sink Current | A4 5 | 16 B3 |
| • | Output Voltage Swing Limited to 3.7 V | A5 [] 6 | 15 B4 |
| | | A6 [] 7 | 14 B5 |
| • | SCR Latch-Up-Resistant BiCMOS Process | A7 🛛 8 | 13 B6 |
| | and Circuit Design | A8 🛛 9 | 12 B7 |
| | Package Options Include Plastic | GND [10 | 11 🛛 B8 |
| | Small-Outline (M) and Shrink Small-Outline | | |
| | (SM) Packages and Standard Plastic (E) DIP | | |

description

The CD74FCT245 is an octal bus transceiver with 3-state outputs using a small-geometry BiCMOS technology. The output stages are a combination of bipolar and CMOS transistors that limit the output high level to two diode drops below V_{CC} . This resultant lowering of output swing (0 V to 3.7 V) reduces the power-bus ringing [a source of electromagnetic interference (EMI)] and minimizes V_{CC} bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 64 mA.

The CD74FCT245 allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The CD74FCT245 is characterized for operation from 0°C to 70°C.

| [| INP | UTS | OPERATION |
|---|-----|-----|-----------------|
| | OE | DIR | OPERATION |
| ſ | L | L | B data to A bus |
| | L | Н | A data to B bus |
| | Н | Х | Isolation |

FUNCTION TABLE



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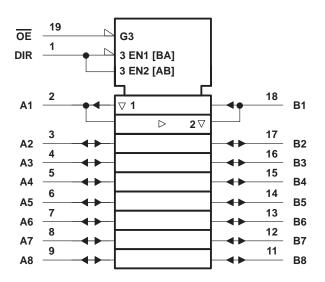
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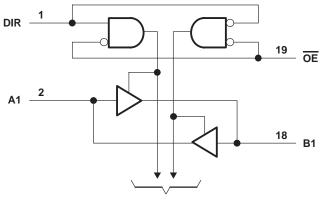
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



To Seven Other Channels



CD74FCT245 BICMOS OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS

SCBS721 - JULY 2000

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

| DC supply voltage range, V_{CC} . DC input clamp current, I_{IK} ($V_I < -0.5 V$) DC output clamp current, I_{OK} ($V_O < -0.5 V$) DC output sink current per output pin, I_{OL}) DC output source current per output pin, I_{OH}) Continuous current through V_{CC} , I_{CC}) Continuous current through GND) Package thermal impedance, θ_{JA} (see Note 1): E package) M package) | 20 mA 50 mA 50 mA 30 m |
|--|---|
| SM package) | |
| Storage temperature range, T _{stg}) | |

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 2)

| | | MIN | MAX | UNIT |
|---------------------|------------------------------------|------|------|------|
| Vcc | Supply voltage | 4.75 | 5.25 | V |
| VIH | High-level input voltage | 2 | | V |
| VIL | Low-level input voltage | | 0.8 | V |
| VI | Input voltage | 0 | VCC | V |
| Vo | Output voltage | 0 | VCC | V |
| ЮН | High-level output current | | -15 | mA |
| IOL | Low-level output current | | 64 | mA |
| $\Delta t/\Delta v$ | Input transition rise or fall rate | 0 | 10 | ns/V |
| Т _А | Operating free-air temperature | 0 | 70 | °C |

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | Vee | T _A = 25°C | MIN MAX | UNIT |
|--------------------|--|--------|-----------------------|---------|------|
| PARAMETER | TEST CONDITIONS | Vcc | MIN MAX | | |
| VIK | I _I = -18 mA | 4.75 V | -1.2 | -1.2 | V |
| VOH | $I_{OH} = -15 \text{ mA}$ | 4.75 V | 2.4 | 2.4 | V |
| VOL | I _{OL} = 64 mA | 4.75 V | 0.55 | 0.55 | V |
| lı | $V_{I} = V_{CC} \text{ or } GND$ | 5.25 V | ±0.1 | ±1 | μΑ |
| I _{OZ} | $V_{O} = V_{CC}$ or GND | 5.25 V | ±0.5 | ±10 | μΑ |
| I _{OS} ‡ | $V_{I} = V_{CC} \text{ or } GND, \qquad V_{O} = 0$ | 5.25 V | -60 | -60 | mA |
| ICC | $V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$ | 5.25 V | 8 | 80 | μΑ |
| ΔI _{CC} § | One input at 3.4 V, Other inputs at V _{CC} or GND | 5.25 V | 1.6 | 1.6 | mA |
| Ci | $V_{I} = V_{CC} \text{ or } GND$ | | 10 | 10 | pF |
| Co | $V_{O} = V_{CC}$ or GND | | 15 | 15 | pF |

[‡]Not more than one output should be tested at a time, and the duration of the test should not exceed 100 ms.

§ This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.



CD74FCT245 BICMOS OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS SCBS721 - JULY 2000

switching characteristics over recommended operating conditions (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM | то | T _A = 25°C | MIN | MAX | UNIT |
|------------------|---------|----------|-----------------------|-----|-----|------|
| FARAMETER | (INPUT) | (OUTPUT) | TYP | | WAA | UNIT |
| ^t pd | A or B | B or A | 5 | 1.5 | 7 | ns |
| ten | OE | A or B | 6 | 1.5 | 9.5 | ns |
| ^t dis | OE | A or B | 6 | 1.5 | 7.5 | ns |

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C

| | PARAMETER | MIN | TYP | MAX | UNIT |
|--------------------|---|-----|-----|-----|------|
| V _{OL(P)} | Quiet output, maximum dynamic V _{OL} | | 1 | | V |
| VOH(V) | Quiet output, minimum dynamic V _{OH} | | 0.5 | | V |
| VIH(D) | High-level dynamic input voltage | 2 | | | V |
| V _{IL(D)} | Low-level dynamic input voltage | | | 0.8 | V |

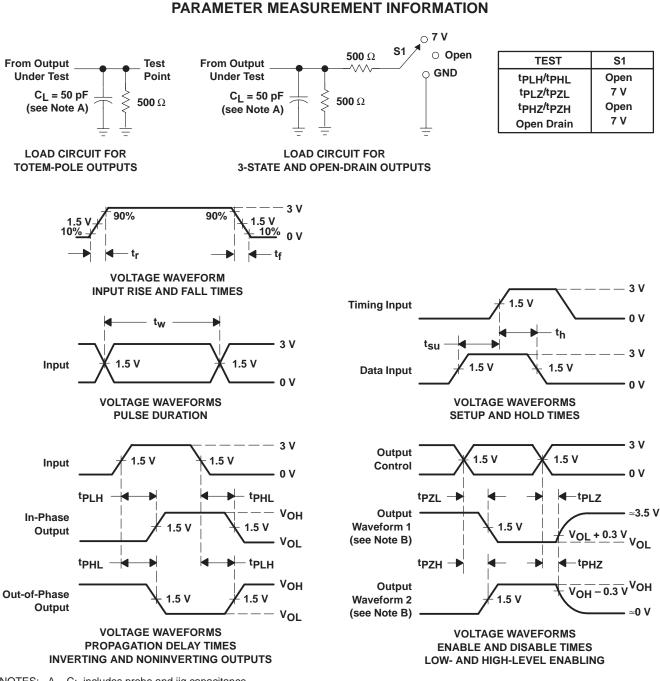
operating characteristics, $T_A = 25^{\circ}C$

| PARAMETER | | ONDITIONS | TYP | UNIT |
|---|----------|-----------|-----|------|
| C _{pd} Power dissipation capacitance | No load, | f = 1 MHz | 49 | pF |

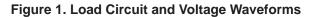


CD74FCT245 BICMOS OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS

SCBS721 - JULY 2000



- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: $PRR \le 1$ MHz, $Z_O = 50 \Omega$, t_f and $t_f = 2.5$ ns. D. The outputs are measured one at a time with one input transition per measurement.
 - D. The outputs are measured one at a tir
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PHL} and t_{PLH} are the same as t_{pd} .







PACKAGING INFORMATION

| Orderable Device | Status | Package Type | | Pins | Package | Eco Plan | Lead finish/ | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|---------|--------------|---------|------|---------|---------------------|---------------|--------------------|--------------|----------------|---------|
| | (1) | | Drawing | | Qty | (2) | Ball material | (3) | | (4/5) | |
| | | | | | | | (6) | | | | |
| CD74FCT245E | ACTIVE | PDIP | Ν | 20 | 20 | RoHS & Non-Green | NIPDAU | N / A for Pkg Type | 0 to 70 | CD74FCT245E | Samples |
| CD74FCT245M | LIFEBUY | SOIC | DW | 20 | 25 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 74FCT245M | |
| CD74FCT245M96 | ACTIVE | SOIC | DW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 74FCT245M | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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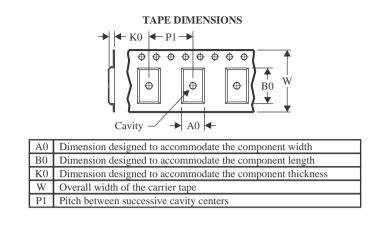
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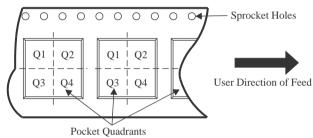
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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



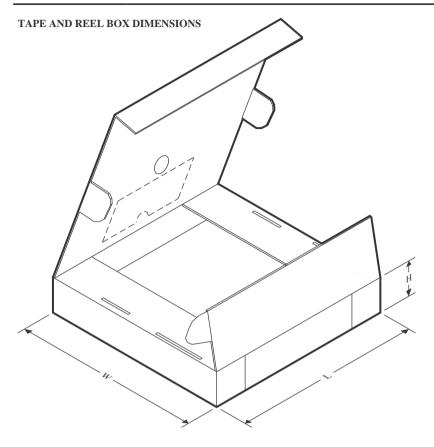
| | Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | ` ' | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|--------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------|------------|------------|------------|-----------|------------------|
| C | 074FCT245M96 | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.8 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |



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PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CD74FCT245M96 | SOIC | DW | 20 | 2000 | 367.0 | 367.0 | 45.0 |

TEXAS INSTRUMENTS

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TUBE



- B - Alignment groove width

*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | Τ (μm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| CD74FCT245E | N | PDIP | 20 | 20 | 506 | 13.97 | 11230 | 4.32 |
| CD74FCT245M | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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